

N-Channel Enhancement Power Mosfet Specification

Features

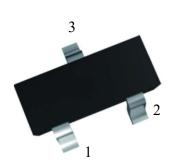
- ·Advanced trench cell design
- ·High speed switch

Applications

- ·Portable appliances

·Notebook/PC appliances ·Power Management ·DC/DC Converter

SOT-23



1: Gate 2: Source 3: Drain

Quick reference

 $BV \ge 60 \text{ V} \quad \text{Id}=2.3\text{A}$

 $R_{DS(ON)} \le 100 \text{ m}\Omega \text{ (a) } V_{GS} = 10 \text{ V}$

 $R_{DS(ON)} \le 120 \text{ m}\Omega \text{ (a) } V_{GS} = 5 \text{ V}$

Limiting Values

Symbol	Parameter	Rating	Unit	
V_{DSS}	Drain-Source Voltage	60	V	
V_{GSS}	Gate-Source Voltage	± 20	V	

REV.08 1 of 2



Electrical Characteristics (Ta = 25°C Unless Otherwise Noted)

Symbol	Parameter	Conditions		Min	Тур	Max	Unit			
Static Characteristics										
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{DS} = 250 \mu\text{A}$		60	-	-	V			
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_{DS} = 250 \mu A$		1.0	1.6	2.5	٧			
I _{DSS}	Drain Leakage Current	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$		-	-	1	μΑ			
			T _J = 85 °C	-	-	30	μΑ			
I _{GSS}	Gate Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V		-	-	± 100	nΑ			
R _{DS(ON)} ^a	On-State Resistance	V_{GS} = 10 V, I_{DS} = 0.5A		-	-	100	mΩ			
		V _{GS} = 5 V, I _{DS} = 0.5 A		-	-	120				
Diode Characteristics ^b										
V _{SD}	Diode Forward Voltage	I _{SD} = 0.5 A, V _{GS} = 0V		-	0.7	1.3	٧			

Notes:

This wafer must be stored at N2 box (RH<20 %).

Wafer must be completely assembled within two months.

a : CP measured on wafer by probe card. (RDS(ON) depended on packaged type and amount of bonding wires)

b : Pulse test ; pulse width $\, \leqslant \, 300 \, \mu \, \text{s}$, duty cycle $\, \leqslant \, 2\%$

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